Quantum Fluctuations and the Exchange Bias Field

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A bstract

Ground-state uctuations reduce the zero-tem perature magnetic moments of the spins in a quantum antiferrom agnet. In the neighborhood of surfaces, interfaces, and other defects which break translational sym metry, these uctuations are not uniform. Because of this the magnetic moments of up and down spins do not exactly compensate each other as they do in a bulk antiferrom agnet. At a surface or interface this leads to a small magnetic dipole density. The corresponding dipole eld can account for the magnitude of observed exchange elds. At nite temperatures localized surface (interface) excitations are populated and change the dipole density. This gives rise to the temperature-dependence of the exchange eld. We expect the uctuation-induced surface dipole density to play a role in the magnetic properties of antiferrom agnetic nano-particles, as well.

Exchange anisotropy arises when two di erently ordered magnetic materials, which are in contact, are cooled in an external magnetic eld through their ordering temperatures. It has been observed, for example, in clusters or small particles, ferromagnetic (FM) lms deposited on single-crystal or polycrystalline antiferromagnetic (AF) substrates, FM/AF thin lm bilayers, and spin glasses. In these systems the center of the hysteresis loop is shifted by an amount called the exchange bias eld. With the convention that the positive eld direction is that of the cooling eld, this exchange bias is, in most cases, negative.

Although exchange anisotropy has attracted the attention of physicists and materials scientists for almost half a century [1, 2, 3, 4] and has resulted in extensive technological applications in the storage and sensor industries [5], a full understanding of its physical origin has not been achieved.

From the experimental results, it is now certain that the e ect is due to a xed spin arrangement on the antiferrom agnetic side of the interface [6, 7, 8]. However, the nature of this arrangement, and the microscopic mechanism leading to the exhange bias eld are still open questions. Most of the theoretical work has made use of the classical Heisenberg model in various forms [4], an exception being the contribution of Suhland Schuller [9], who have interpreted the exchange eld as a self-energy shift due to the emission and reabsorption of antiferrom agnetic spin waves. Recently, a theory based on the Dzyaloshinsky-Moriya interaction has been put forward by Ijiry et al [10].

In this letter we argue that quantum uctuations lead to a two-dim ensional dipole moment density at the ferrom agnetic-antiferrom agnetic interface. The magnetic eld due to this dipole density can explain exchange bias.

Why are quantum uctuations relevant to the physics of antiferrom agnets? Let us brie y consider this question in the case of a two-sublattice antiferrom agnet. The order parameter relevant here is the staggered magnetization: $\langle \hat{M}_{AF} \rangle = g_B \langle \hat{P}_{S} \rangle \hat{S} \rangle$, where \hat{S} and \hat{S} denote the spin operators at the spin-up and spin-down sub-lattices. If we assume a Heisenberg Ham iltonian $\hat{H} = \hat{P}_{ij} J_{ij} \hat{S}_i \hat{S}_j$, we can see that \hat{M}_{AF} ; $\hat{H} \in \mathbb{R}$ 0, in other words, that \hat{M}_{AF} is not constant in time. Therefore its time-averaged value must be smaller than its maximum value, even at $\hat{H} = 0$. (If $\hat{H} = 0$ is the number of spins and $\hat{H} = 0$ is the spin magnitude, this maximum value is $\hat{H} = 0$.) In a translationally invariant system the reduction of the magnetization is equally shared by all spins. Moreover, since the spin up and spin down sublattices are equivalent then $\hat{H} = 0$ is $\hat{H} = 0$.

m om ent is zero. But when translational sym m etry is broken by surfaces, interfaces, or other defects, a nite m agnetic m om ent can appear because the decrease of spin-up averages need not equal the corresponding spin-down reduction [11, 12, 13]. In the calculations outlined below we not that the magnitude of this magnetic moment is only a few percent of that of a fully uncompensated spin, which is consistent with the experimental results.

Let us now focus on a speci c model, in which atom ic spins of magnitude $^{\circ}$ S (S + 1) are located at the sites of a bcc lattice. This system is assumed to be divided in two halves by a (001) interface. To the left of the interface, nearest neighbor spins are coupled ferrom agnetically by the exchange integral J_F . To the right, nearest neighbor spins are coupled antiferrom agnetically by the exchange integral J_A . A cross the interface, spins are coupled by the exchange integral J_O . Here we exam the three cases, with $J_O < 0$, $J_O > 0$, and $J_O = 0$, respectively. The latter corresponds to a free antiferrom agnetic surface.

We decompose the box lattice into planes parallel to the interface. In the antiferrom agnetic side, each of these planes is ferrom agnetic and its spin direction alternates from one plane to the next; we group these planes in pairs an label each pair with the index 1 - 0, in such a way that 1 = 0 labels the pair of planes closest to the interface; for each pair we label the corresponding planes with the subscript—for spins up, and the label—for spins down. In the ferrom agnetic side each index (1 < 0) denotes a single, spin up, layer. This choice of notation rejects the fact that in the antiferrom agnet the unit cell is doubled. The Ham iltonian can be written as:

$$H = \begin{cases} X^{1} & X \\ & [J_{1;1}S & (1;R) & S(1;R+) + J_{1;1+1}S & (1;R+) & S(1+1;R)] + \\ & & X^{1} & X \\ & & & J_{1;1+1}S & (1;R+) & S(1+1;R); \end{cases}$$

$$= 1 R;$$
(1)

where $R = a(n_1 \hat{x} + n_2 \hat{y})$ is a two-dim ensional lattice point, a is the lattice constant, n_1 and n_2 are integers, $= a(\hat{x} + \hat{y})$, and $S_a(l;R)[S_b(l;R)]$ is a spin in the () plane of the l-th pair (and at site R in that plane).

We now use the Holstein-Primako transformation to rewrite the Hamiltonian in terms of boson operators a and b:

$$S_a^z(l;R) = S \quad a^y(l;R) a(l;R);$$
 (2)

$$S_a^+$$
 (l;R) = [2S a^y (l;R) a (l;R)]¹⁼² a (l;R); (3)

$$S_b^z(1;R) = S + b^y(1;R)b(1;R);$$
 (4)

and

$$S_b(1;R) = [2S b^y(1;R)b(1;R)]^{1-2}b(1;R);$$
 (5)

We neglect spin wave interactions and therefore we discard quartic and higher order terms. To take advantage of the translational symmetry we dene:

$$a(l;k) = \frac{1}{P} \frac{X}{N} a(l;R) \exp(ik R)$$
 (6)

and

$$b(l;k) = \frac{1}{P} \sum_{N=0}^{X} b(l;R) \exp(ik R);$$
 (7)

The last transform ation separates the H am iltonian into a sum of H am iltonians, one for each value of the two-dim ensional wavector k. Each of these H am iltonians can be thought of as describing a one-dim ensional chain, the parameters of which depend on k only through the function $k = \cos(k_x=2)\cos(k_y=2)$. Once this separation is made, ground-state properties become sum sover k. One-dimensional chains are conveniently analyzed using G reen functions, which we now dene:

$$G_{110}^{aa} = \frac{i^{Z_{1}}}{h} dte^{i!t} (t)h[a(1;k;t);a^{Y}(1^{0};k;0)]i$$
 (8)

where hA i denotes the therm all average of A and the operators are in the Heisenberg representation. We do not the functions G_{110}^{bb} , G_{110}^{ab} , and G_{110}^{ba} in the same fashion. The average spin at plane 1 is given by

$$hS_{l;a}^{z}i = S + \sum_{k=1}^{X} \frac{1}{m} \sum_{l=1}^{Z} d! \frac{G_{ll}^{aa}(!; k)}{e^{h! = k_B T} 1}$$
 (9)

$$hS_{1;b}^{z}i = S$$
 $\int_{k}^{X} \frac{1}{1} Im \int_{1}^{Z} d! \frac{G_{11}^{bb}(!;k)}{e^{h!=k_B T} 1}$ (10)

The spectral distributions $\frac{1}{2}$ Im G in Equations 9 and 10 contain the contributions of interface and bulk excitations. The interface excitations are localized in a few layers about

interface. They appear for all values of the model parameters and dominate the spin reduction, and hence the net magnetization, at the interface W hen T=0 the integrands in 9 and 10 are zero for ! > 0. The negative !-axis gives the e ect of virtual spin waves on ground-state uctuations [13]. At nite temperatures real spin waves are excited which further change the net magnetization.

In gures 1 and 2 we show the magnetization per unit cell in the antiferrom agnetic side of the interface. In both cases, the maximum net magnetization is of the order of a few percent of that of an atom ic spin. In gure 1 the coupling across the interface is ferrom agnetic and the net magnetization is parallel to the ferrom agnetic moments. In gure 2 the coupling across the interface is antiferrom agnetic and the net magnetization is antiparallel to that of the ferrom agnet. In general, we not that for $jJ_0j < jJ_Aj$ the net magnetization of the antiferrom agnet is of the order of a few percent of that of an atom ic spin.

The magnetic moments of the antiferrom agnetic spins produce a dipolar magnetic eld. This is a long range e ect. We can estimate the magnitude of this eld assuming that the net magnetization is uniformly distributed at a single layer. If we take this layer to be a disk of radius R, the eld at a distance z on the axis is given by B (z) = $(_{0}g_{B} S=Ra^{2})(1+z^{2}=R^{2})^{3=2}$. With R 1 nm, S 10 2 , and the lattice constant a 0:1 nm, we not that B (0) 10^{3} oersted.

The magnetic moment is, again, of the order of a few percent of that of an uncompensated monolayer, as has been observed by Takano et al. [15] in CoO/MgO multilayers. For this particular system the sign of the exchange eld reverses. Such kind of reversal has been experimentally observed [14].

In sum mary, we have shown that the dipole eld generated by uncompensated quantum uctuations can account for the observed exchange bias elds. The temperature dependence is explained in terms of the excitation of surface spin waves which, for low enough temperatures, can be accounted for by our linear theory. Finally, since we not that pure antiferrom agnets develop a surface magnetic moment, our theory could be tested by experim ental studies of clean antiferrom agnetic surfaces.

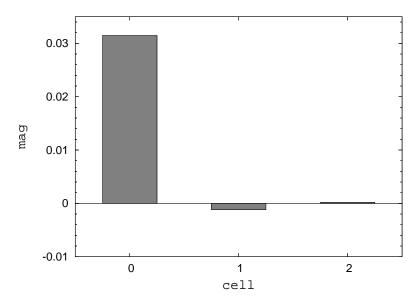


FIG. 1: Net m agnetization per unit cell in the antiferrom agnetic side of the interface. The index cell denotes a pair of layers of opposite spins. In units such that $J_A + J_F = 1$, the parameters are $J_A = 0.615$, $J_F = 0.385$, and $J_0 = 0.5$.

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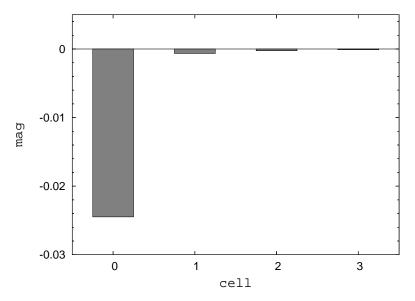


FIG .2: Net m agnetization per unit cell near the antiferrom agnetic side of the interface. The index cell denotes a pair of layers of opposite spins. In units such that $J_A + J_F = 1$, the parameters are $J_A = 0.17$, $J_F = 0.83$, and $J_0 = 0.08$.

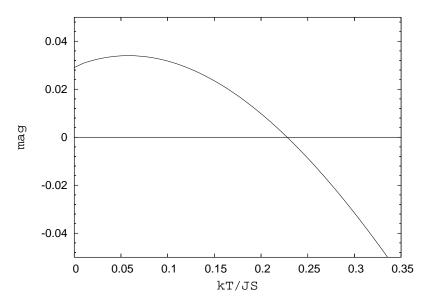


FIG .3: Surface m agnetization as a function of k_B T=JS To m odel the surface we take $J_0=0$

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